

1N4001 thru 1N4007

REV. 9, MAY-2015, KDAC01

REVERSE VOLTAGE – 50 to 1000 Volts PLASTIC SILICON RECTIFIERS **FORWARD CURRENT – 1.0 Ampere FEATURES** DO - 41 · Low cost Diffused junction А В А · Low forward voltage drop · Low reverse leakage current • High current capability - C A D **MECHANICAL DATA** • Case: JEDEC DO-41, molding compound has DO - 41 UL flammability classification 94V-0 MAX DIM MIN • Polarity: Color band denotes cathode Α 25.4 5.20 В 4.10 • Weight: 0.012 ounces, 0.34 grams С 0.71 Ø 0.86 Ø Mounting Position: Any D 2.00 Ø 2.70 Ø All dimension in millimeter

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

| ABSOLUTE RATINGS | | | | | | | | | | |
|--|-----------------|-------------------|-------------|--------|--------|--------|--------|------------------|--------|------|
| PARAMETER | | SYMBOL | 1N4001 | 1N4002 | 1N4003 | 1N4004 | 1N4005 | 1N4006 | 1N4007 | UNIT |
| Maximum repetitive peak reverse voltage | | V _{RRM} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum DC blocking voltage | | V _{DC} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Average rectified output current per device @T _A =75 [°] C | | I _(AV) | 1.0 | | | | | Α | | |
| Peak forward surge current 8.3ms single half sine-wave superimposed on rated load | | I _{FSM} | 30 | | | | | А | | |
| I^2 t rating for fusing (t = 8.3ms) | | l²t | 3.7 | | | | | A ² S | | |
| Operating temperature range | | TJ | -55 to +125 | | | | | °C | | |
| Storage temperature range | | T _{STG} | -55 to +150 | | | | | °C | | |
| STATIC ELECTRICAL | CHARACTERISTICS | | | | | | | | | |
| PARAMETER | TEST CONDITION | SYMBOL | . MAX. | | | | UNIT | | | |
| | | | | | | | | | | |

| Forward voltage | I _F = 1.0A | T _J = 25°C | V _F | 1.0 | V |
|---------------------------------------|-----------------------|---|----------------|----------|----|
| Leakage current | V_{R} at rated | T _J = 25°C T _J = 100°C | I _R | 10 50 | uA |
| Typical junction capacitance (Note 1) | | C」 | 15 | pF | |

THERMAL CHARACTERISTICS

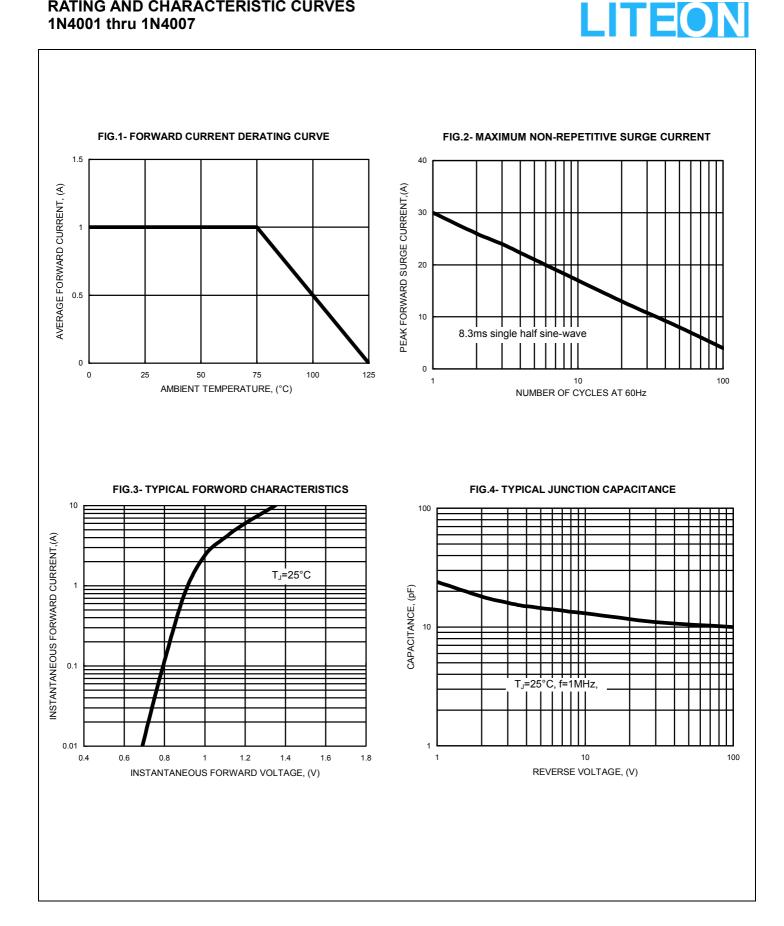
| PARAMETER | | SYMBOL | TYP. | | | | | | |
|------------------------------------|---|--|----------|------|------|--|--|--|--|
| Thermal resistance (Note 2) | | RthJ _A RthJ _C | 50 12 | | | | | | |
| DYNAMIC ELECTRICAL CHARACTERISTICS | | | | | | | | | |
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | MAX. | UNIT | | | | |
| Reverse recovery time | IF= 0.5A, I _{RR} = 0.25A, I _R =1.0A | T _{RR} | 0.5 | 5.0 | us | | | | |

Note :

(1) Measured at 1.0MHz and applied reverse voltage of 4.0V DC

(2) Thermal resistance junction to ambient and case,

RATING AND CHARACTERISTIC CURVES 1N4001 thru 1N4007



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